## NSN 5961-01-276-2464

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View Online at https://aerobasegroup.com/nsn/5961-01-276-2464 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.750 inches **Overall Diameter:** 0.370 inches **Function For Which Designed:** Rectifier **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method: Terminal Terminal Circle Diameter:** 0.1414 inches **Features Provided:** Hermetically sealed case and quality assurance level tx **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.0 gate trigger voltage, dc and 50.0 reverse voltage, peak **Current Rating Per Characteristic:** 350.00 microamperes forward current, total rms preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnpn **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/276 government specification Shelf Life: N/a

No

**Unit Of Measure:** 

**Demilitarization:** 

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